

Abstract Submitted  
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**RF Impedance of a Spherical Probe at High and Low Gas Pressure**<sup>1</sup> R.F. FERNSLER, D.N. WALKER, SFA, Crofton, MD, D.D. BLACKWELL, W.E. AMATUCCI, Plasma Physics Division, Naval Research Laboratory, S.J. MESSER, NRL-NRC Postdoctoral Associate — The plasma electron density  $n_{eo}$  is most often determined using a Langmuir probe to measure the dc current as a function of the applied dc voltage  $V_{dc}$ . The dc impedance  $Z_{dc}$  varies strongly with  $V_{dc}$ , and models are needed to relate  $Z_{dc}$  to  $n_{eo}$ . Secondary electron emission, ion collisions, and other effects further complicate the analysis. Alternatively, a variable rf voltage can be applied while holding  $V_{dc}$  fixed. As long as the rf voltage is small, the rf impedance  $Z_{rf}$  varies with the frequency  $f$  but not the amplitude of the voltage, and for a fixed frequency,  $Z_{rf}$  depends only on  $n_e(r)$  and the neutral gas density  $N$ . In this talk theoretical and experimental results for  $Z_{rf}$  are related to  $n_{eo}$  for a small spherical probe. At low  $N$ ,  $Z_{rf}$  becomes resistive whenever  $f$  equals the local plasma frequency, and both the real and imaginary parts of  $Z_{rf}$  peak when  $f$  equals the bulk plasma frequency. The peaks make  $n_{eo}$  easy to determine, and the resistance at lower frequencies can be used to determine  $n_e(r)$  within the sheath and presheath. At high  $N$ , the resistance depends mainly on  $n_{eo}/N$ , so  $n_{eo}$  is again easy to determine. Theoretical and experimental results for several spheres will be compared with Langmuir-probe data at high and low gas pressure.

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Richard Fernsler  
Plasma Physics Division, Naval Research Laboratory

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